## NSN 5961-01-043-2704

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-043-2704 **Inclosure Material:** Metal **Overall Length:** 1.250 inches **Overall Height:** 0.295 inches **Overall Width:** 0.700 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 55.0 collector to emitter voltage/static/base open and 90.0 collector to base voltage, dc and 7.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 4.00 amperes source cutoff current and 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 75.0 watts small-signal input power, common-collector absolute **Transfer Ratio:** 180.0 small-signal short-circuit forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure:** 

No

**Demilitarization:** 

## **NSN 5961-01-043-2704** Transistor - Page 2 of 2



Fiig:

A110a0